



Micron Technology

MT47H64M8CB-5E:B

Nambari ya Sehemu:	MT47H64M8CB-5E:B
Mtengenezaji / Brand:	Micron Technology
Maelezo ya bidhaa	IC DRAM 512M PARALLEL 60FBGA
Datasheets:	MT47H64M8CB-5E:B.pdf
Hali ya RoHS	Kuongoza bure / RoHS Inavyotakiwa
Hali	9878 pcs stock
Meli Kutoka	Hong Kong
Njia ya Uhamisho	DHL/Fedex/TNT/UPS/EMS

OMBI LA NUKUU

Picha inaweza kuwa uwakilishi. Angalia maelezo ya maelezo ya bidhaa.

Ufafanuzi wa MT47H64M8CB-5E:B

NAMBARI YA SEHEMU	MT47H64M8CB-5E:B
MTENGENEZAJI	Micron Technology
MAELEZO	IC DRAM 512M PARALLEL 60FBGA
HALI YA BURE YA BURE / HALI YA ROHS	Kuongoza bure / RoHS Inavyotakiwa
KIASI INAPATIKANA	9878 pcs
KARATASI YA DATA	MT47H64M8CB-5E:B.pdf
ANDIKA MUDA WA MZUNGUKO - NENO, UKURASA	15ns
UGAVI WA VOLTAGE	1.7 V ~ 1.9 V
TEKNOLOJIA	SDRAM - DDR2
DUKA LA KIFAA CHA WASAMBAZAJI	60-FBGA
MFULULIZO	-
UFUNGAJI	Tray
PAKET / UCHUNGUZI	60-FBGA
JOTO LA UENDESHAJI	0°C ~ 85°C (TC)
AINA YA KUINUA	Surface Mount
KIWANGO CHA SENSITIVITY MOISTURE (MSL)	5 (48 Hours)
AINA YA KUMBUKUMBU	Volatile
UKUBWA WA KUMBUKUMBU	512Mb (64M x 8)
MUUNGANISHO WA KUMBUKUMBU	Parallel
AINA YA KUMBUKUMBU	DRAM
HALI YA BURE YA BURE / HALI YA ROHS	Lead free / RoHS Compliant
MAELEZO YA KINA	SDRAM - DDR2 Memory IC 512Mb (64M x 8) Parallel 200MHz 600ps 60-FBGA
SAA YA SAA	200MHz
NAMBARI YA SEHEMU YA MSINGI	MT47H64M8
MUDA WA UFIKIAJI	600ps

Tags kuhusiana

Micron Technology MT47H64M8CB-5E:B	Mgawanyiko wa MT47H64M8CB-5E:B	Mtoa MT47H64M8CB-5E:B
MT47H64M8CB-5E:B Bei	MT47H64M8CB-5E:B Picha	MT47H64M8CB-5E:B Image
Datasheet ya MT47H64M8CB-5E:B PDF	MT47H64M8CB-5E:B Pakua Datasheet	Datasheet ya MT47H64M8CB-5E:B
MT47H64M8CB-5E:B Stock	Nunua MT47H64M8CB-5E:B	Nunua Micron Technology MT47H64M8CB-5E:B
Micron Technology MT47H64M8CB-5E:B	Mtoa Micron Technology	Mgawanyiko wa Micron Technology
Micron Technology MT47H64M8CB-5E:B	Micron Technology Inc. MT47H64M8CB-5E:B	

Bidhaa zinazohusiana

<p>MT47H64M8CB-5E IT:B TR Wazalishaji: Micron Technology Maelezo: IC DRAM 512M PARALLEL 60FBGA Katika hisa: 7229 pcs</p> <p>RFQ</p>	<p>MT47H64M8CB-5E IT:B Wazalishaji: Micron Technology Maelezo: IC DRAM 512M PARALLEL 60FBGA Katika hisa: 7465 pcs</p> <p>RFQ</p>
<p>MT47H64M8CF-25E AIT:G TR Wazalishaji: Micron Technology Maelezo: IC DRAM 512M PARALLEL 60FBGA Katika hisa: 14574 pcs</p> <p>RFQ</p>	<p>MT47H64M8CB-37V:B TR Wazalishaji: Micron Technology Maelezo: IC DRAM 512M PARALLEL 60FBGA Katika hisa: 2599 pcs</p> <p>RFQ</p>
<p>MT47H64M8CF-25E IT:G Wazalishaji: Micron Technology Maelezo: IC DRAM 512M PARALLEL 60FBGA Katika hisa: 12698 pcs</p> <p>RFQ</p>	<p>MT47H64M8CB-3:B Wazalishaji: Micron Technology Maelezo: IC DRAM 512M PARALLEL 60FBGA Katika hisa: 8878 pcs</p> <p>RFQ</p>
<p>MT47H64M8CF-25E IT:G TR Wazalishaji: Micron Technology Maelezo: IC DRAM 512M PARALLEL 60FBGA Katika hisa: 15181 pcs</p> <p>RFQ</p>	<p>MT47H64M8CF-187E:G Wazalishaji: Micron Technology Maelezo: IC DRAM 512M PARALLEL 60FBGA Katika hisa: 7764 pcs</p> <p>RFQ</p>
<p>MT47H64M8CF-25E AIT:G Wazalishaji: Micron Technology Maelezo: IC DRAM 512M PARALLEL 60FBGA Katika hisa: 11715 pcs</p> <p>RFQ</p>	<p>MT47H64M8CB-5E:B TR Wazalishaji: Micron Technology Maelezo: IC DRAM 512M PARALLEL 60FBGA Katika hisa: 8292 pcs</p> <p>RFQ</p>
<p>MT47H64M8CB-3:B TR Wazalishaji: Micron Technology Maelezo: IC DRAM 512M PARALLEL 60FBGA Katika hisa: 7706 pcs</p> <p>RFQ</p>	<p>MT47H64M8CB-37V:B Wazalishaji: Micron Technology Maelezo: IC DRAM 512M PARALLEL 60FBGA Katika hisa: 2502 pcs</p> <p>RFQ</p>